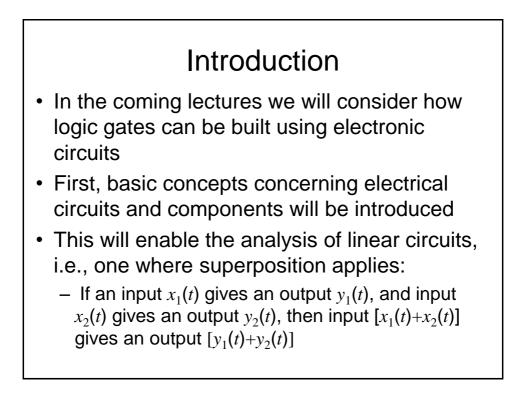
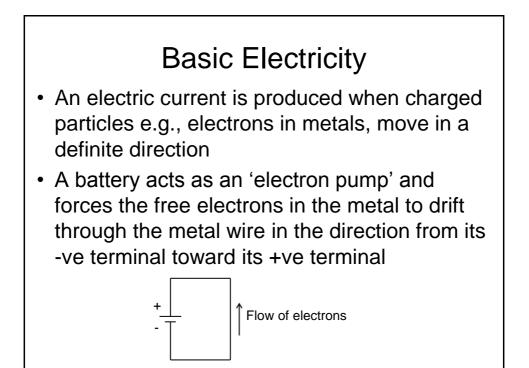
Digital Electronics Part II – Electronics, Devices and Circuits Dr. I. J. Wassell



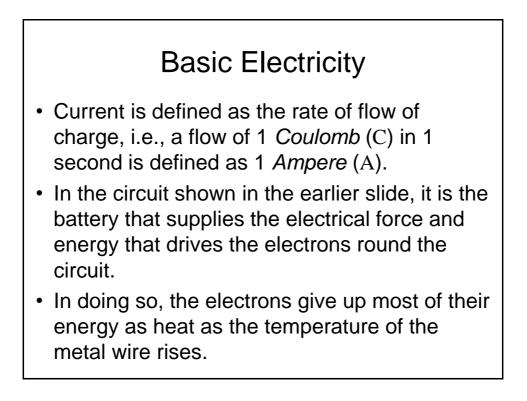
Introduction

- However, logic circuits are non-linear, consequently we will introduce a graphical technique for analysing such circuits
- Semiconductor materials, junction diodes and field effect transistors (FET) will be introduced
- The construction of an NMOS inverter from an n-channel (FET) will then be described
- Finally, CMOS logic built using FETs will then be presented

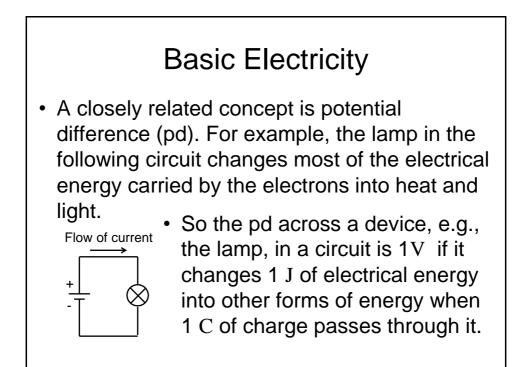


Basic Electricity

- Actually, before electrons were discovered it was imagined that the flow of current was due to positively charged particles flowing out of +ve toward –ve battery terminal
- Indeed, the positive direction of current flow is still defined in this way!
- The unit of charge is the *Coulomb* (C). One Coulomb is equivalent to the charge carried by 6.25*10¹⁸ electrons (since one electron has a charge of 1.6*10⁻¹⁹ Coulombs).

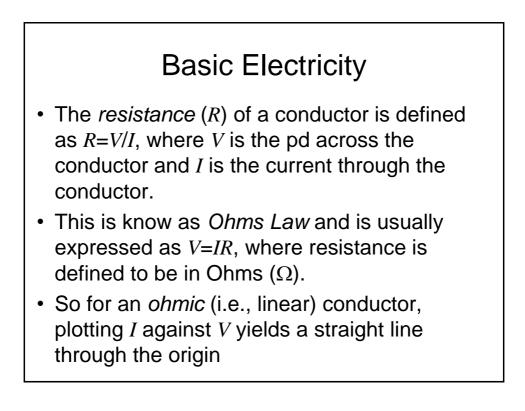


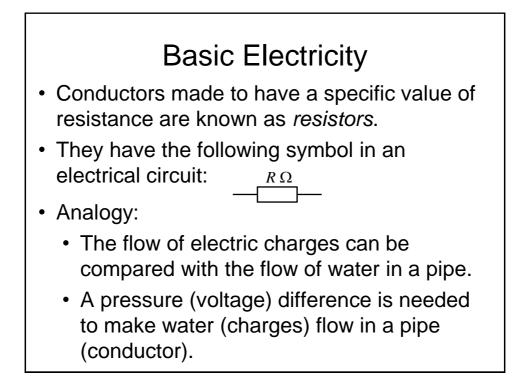
Basic Electricity It can be *imagined* that each Coulomb of charge that leaves the battery receives a fixed amount of electrical energy that depends upon the battery. So the electromotive force (emf) *E* of a battery is defined to be 1 *Volt* (V) if it gives 1 *Joule* (J) of electrical energy to each Coulomb passing through it.

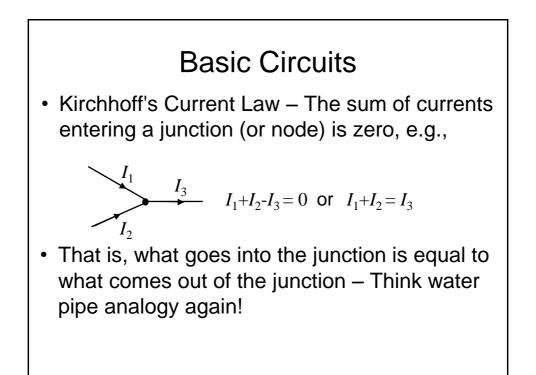


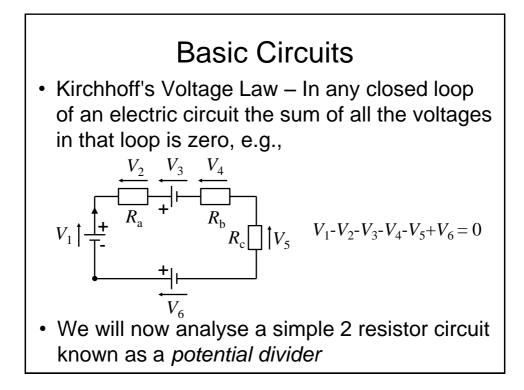
Basic Electricity

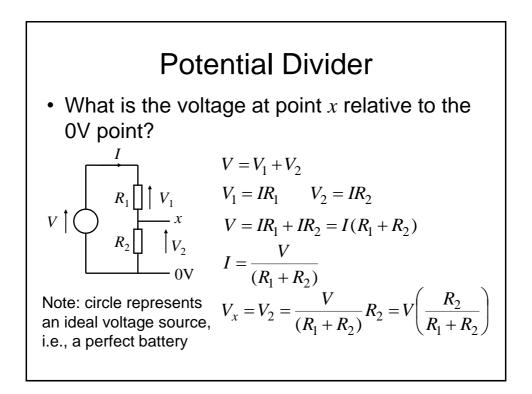
- Note that pd and emf are usually called *voltages* since both are measured in V.
- Electrical engineers have an alternative (but essentially equivalent) view concerning pd.
- That is, conductors, to a greater or lesser extent, oppose the flow of current. This 'opposition' is quantified in terms of *resistance* (*R*). Thus the greater is the resistance, the larger is the potential difference measured across the conductor.

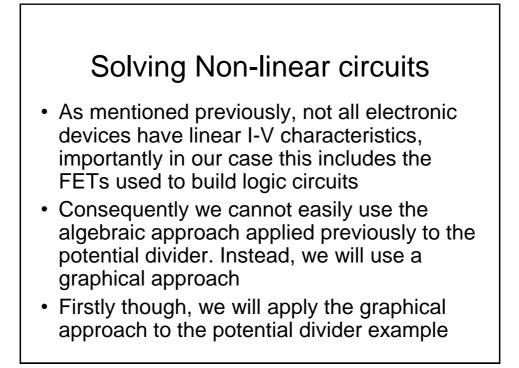


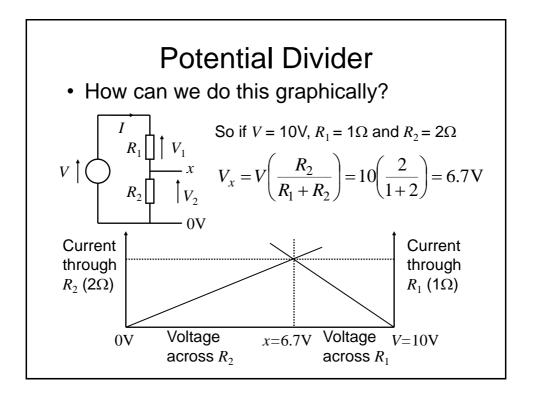


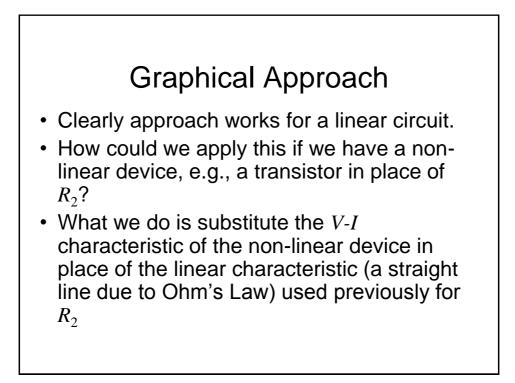


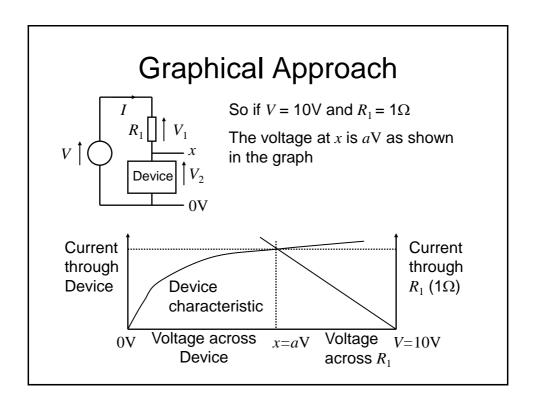


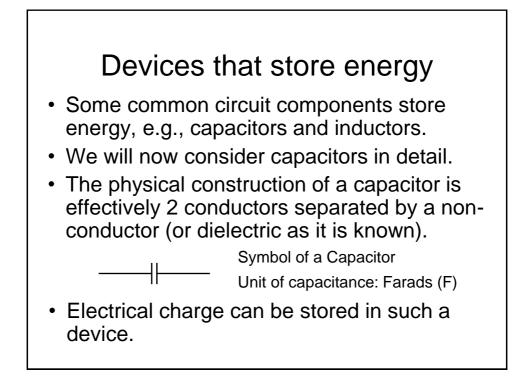


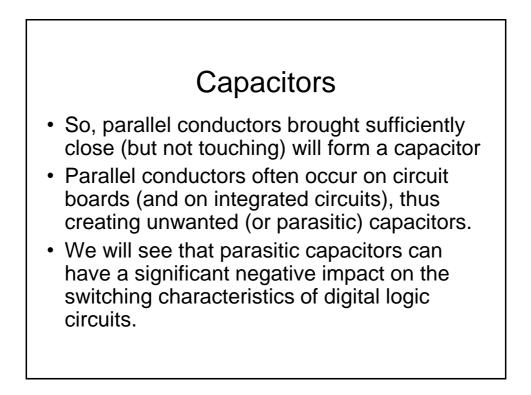


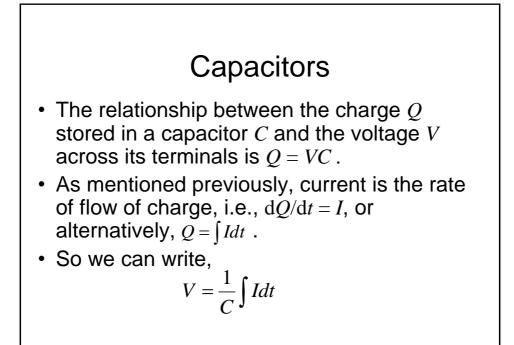


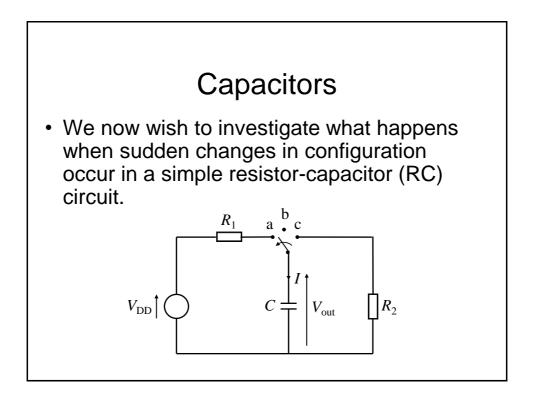


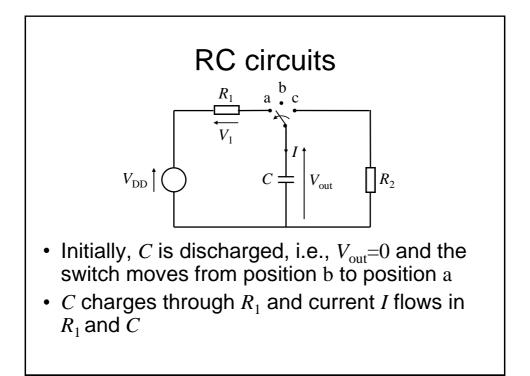


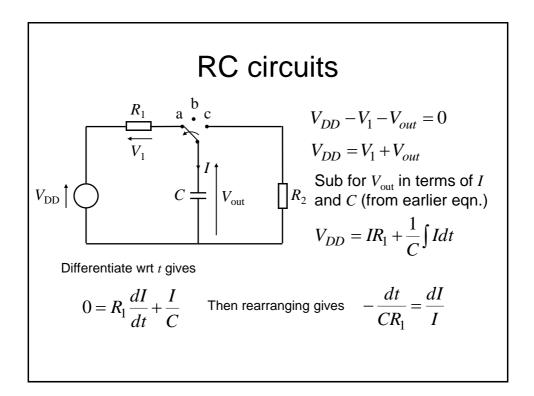


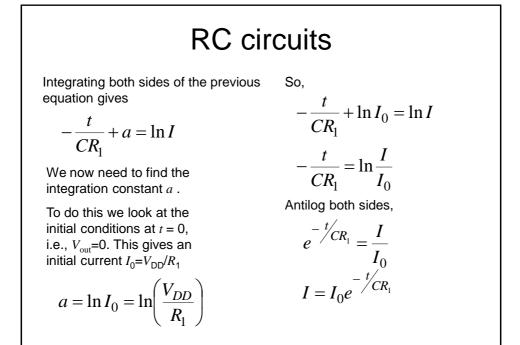


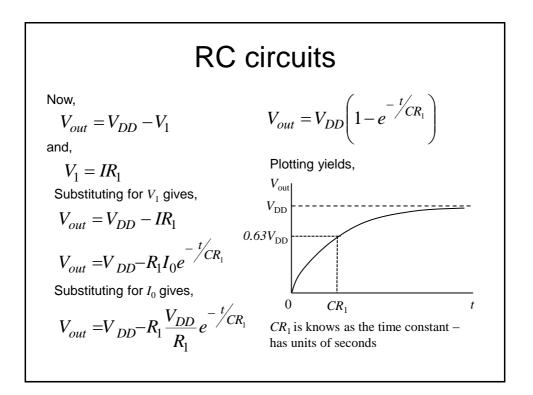


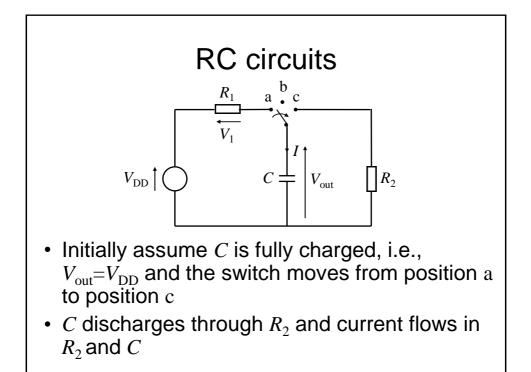


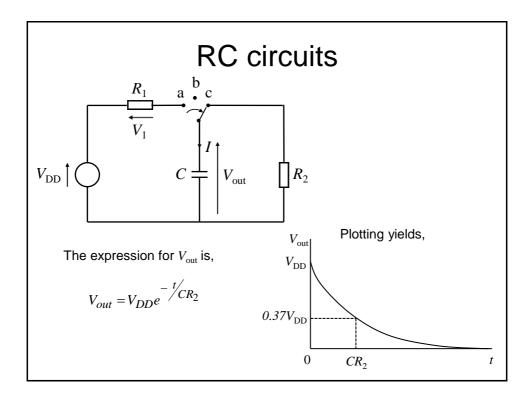






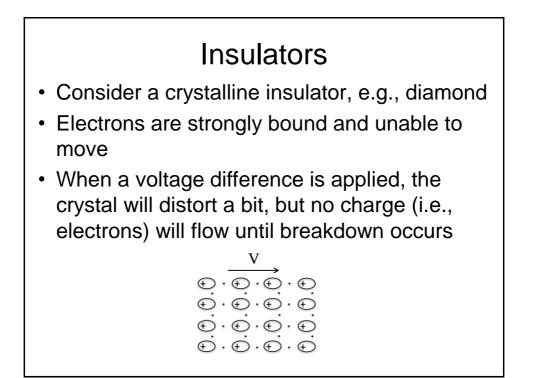


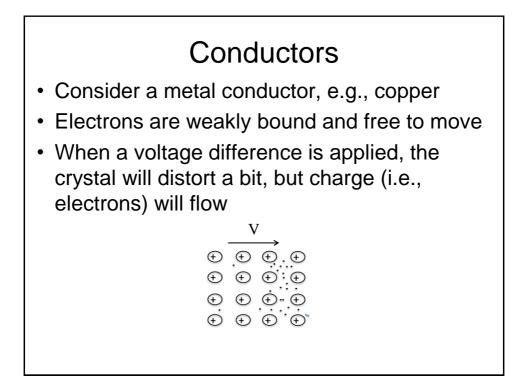


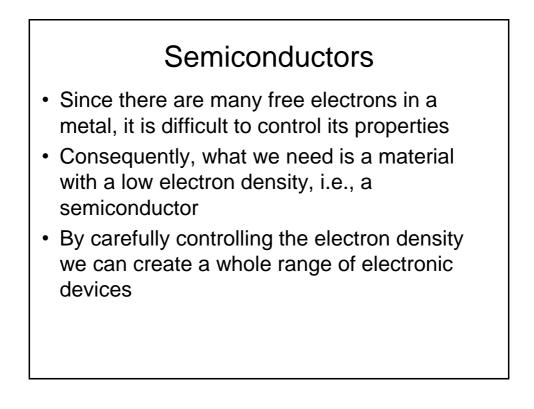


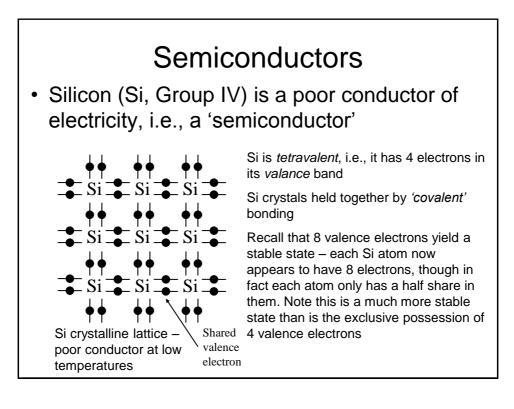
Basic Materials

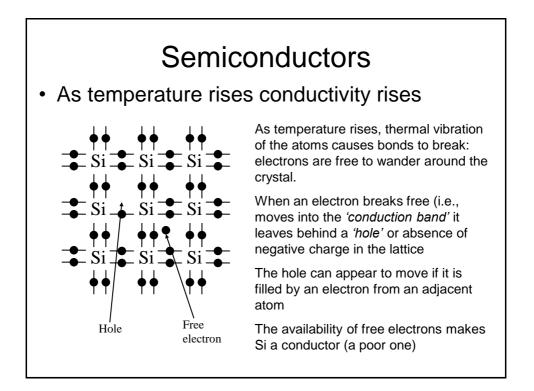
- The electrical properties of materials are central to understanding the operation of electronic devices
- Their functionality depends upon our ability to control properties such as their resistance or current-voltage characteristics
- Whether a material is a conductor or insulator depends upon how strongly bound the outer valence electrons are to their atomic cores

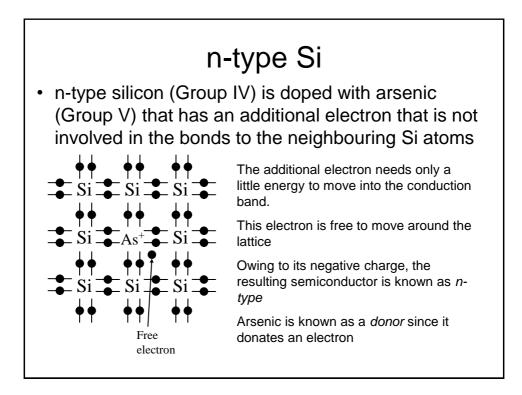


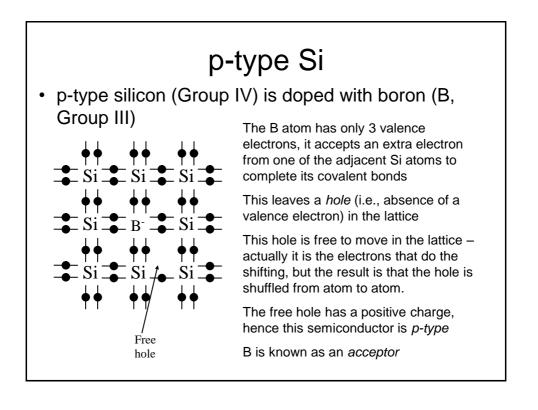


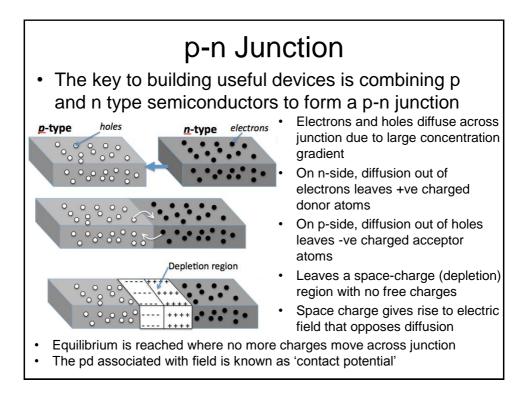


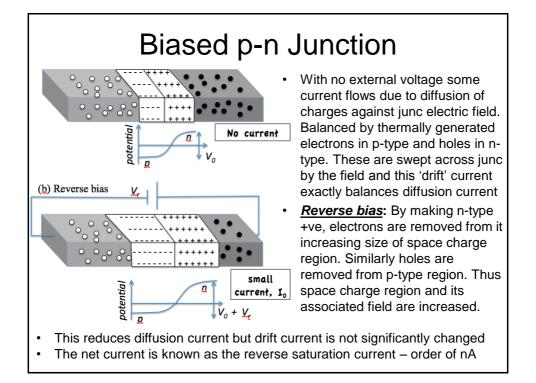


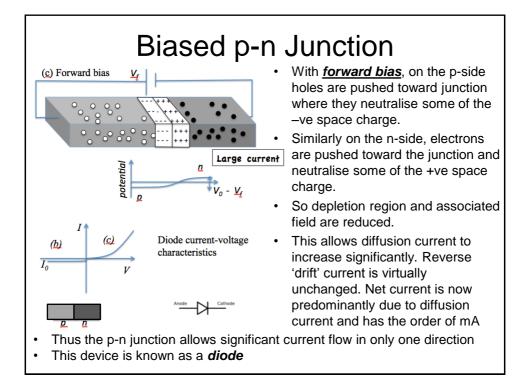


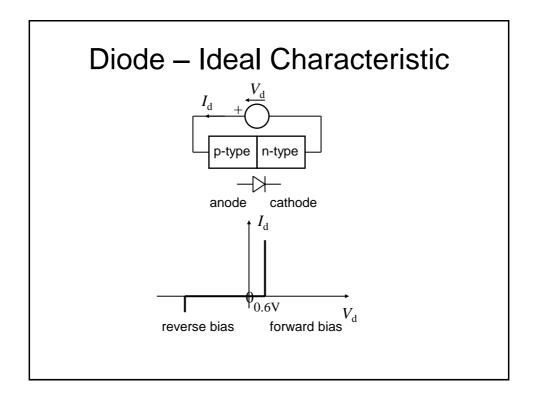


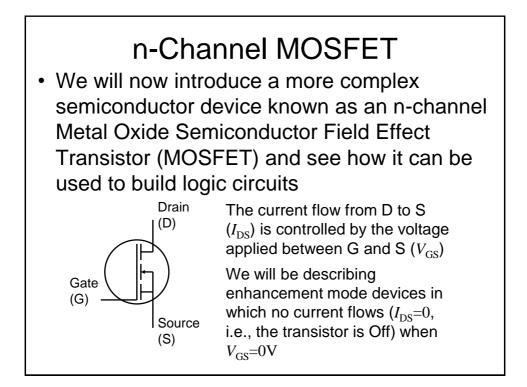


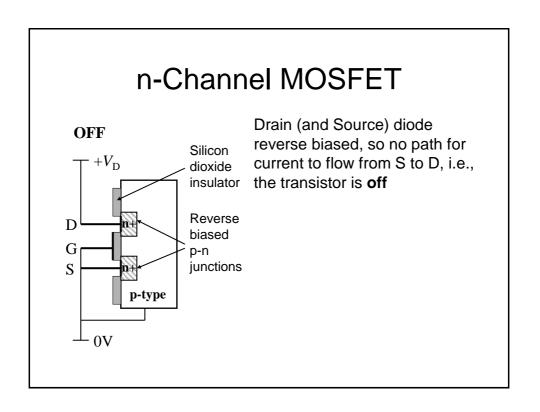


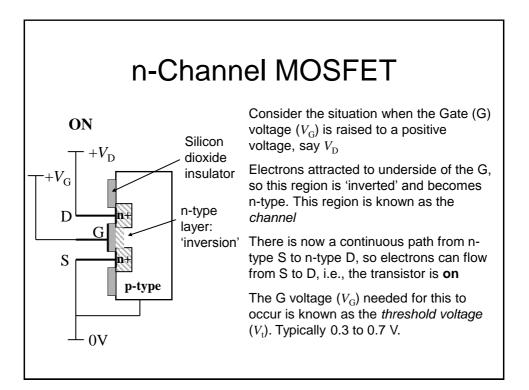


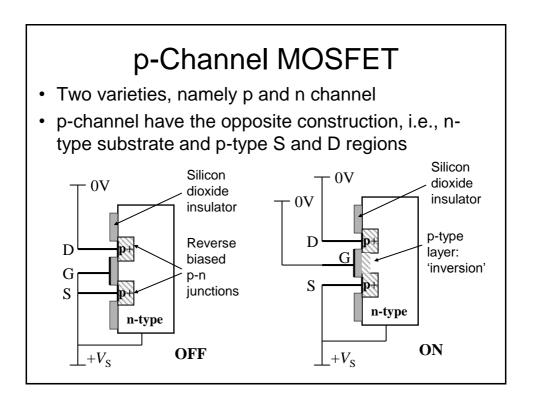


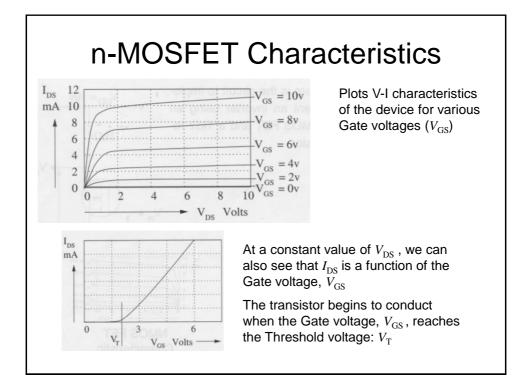


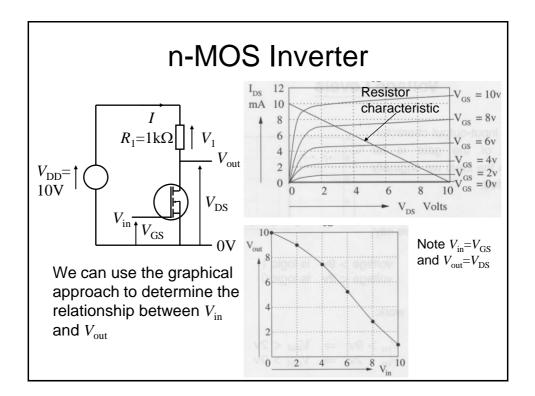


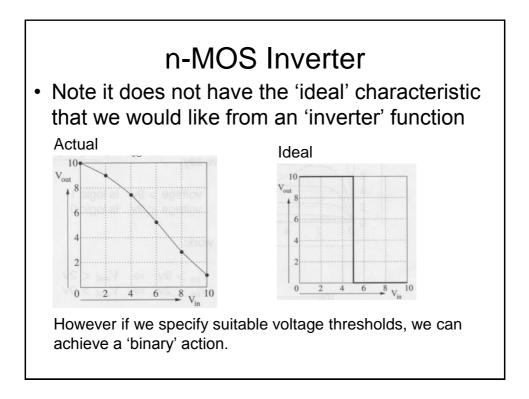


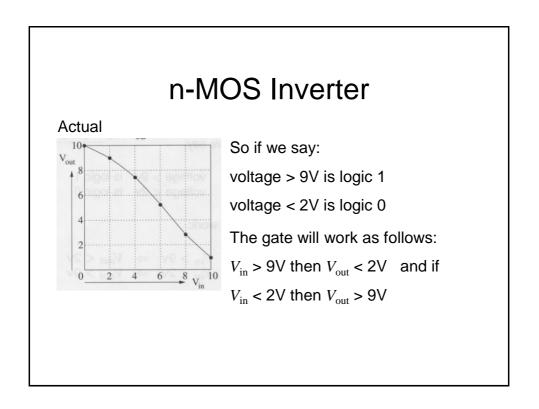






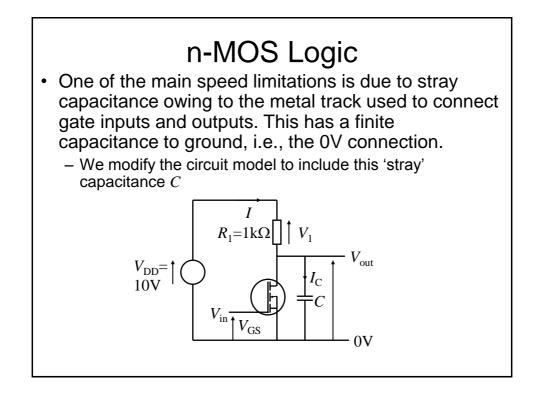


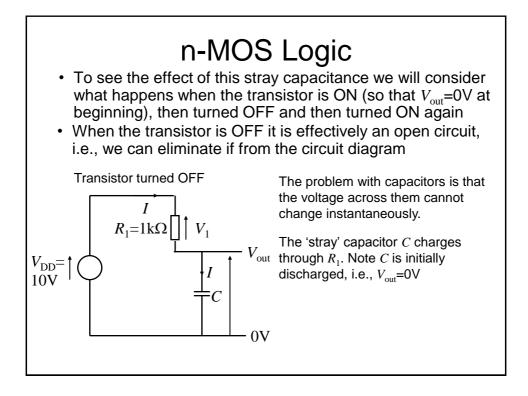


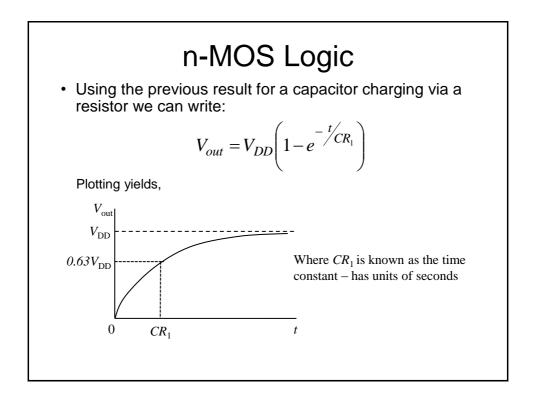


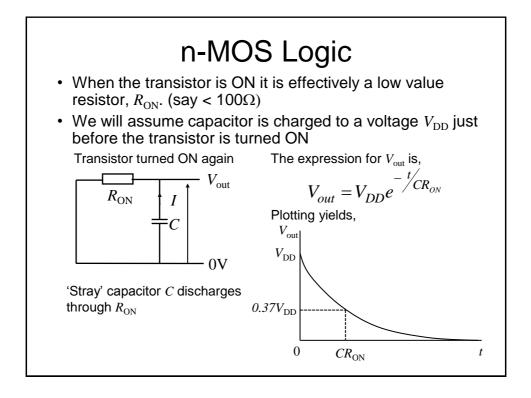
n-MOS Logic

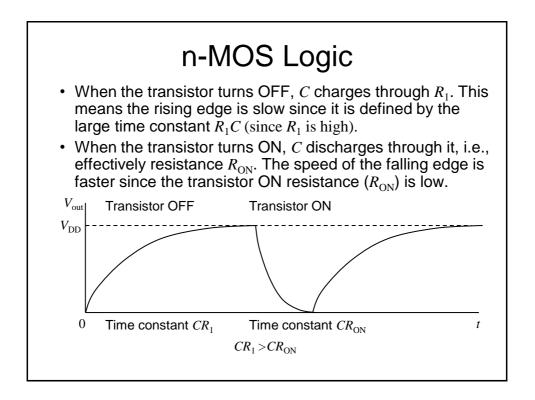
- It is possible (and was done in the early days) to build other logic functions, e.g., NOR and NAND using n-MOS transistors
- However, n-MOS logic has fundamental problems:
 - Speed of operation
 - Power consumption

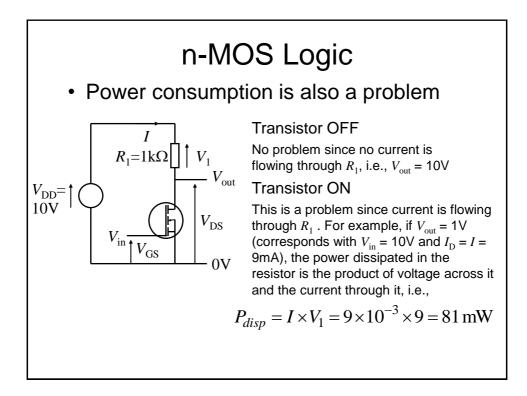


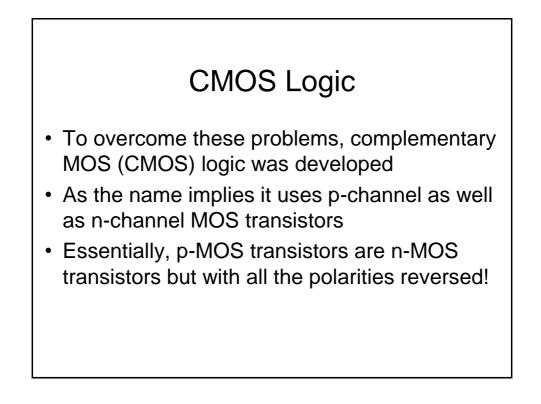


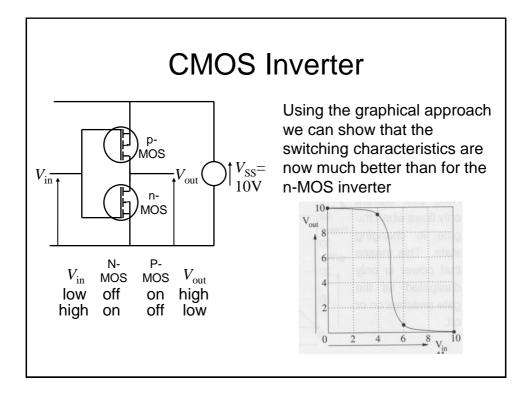


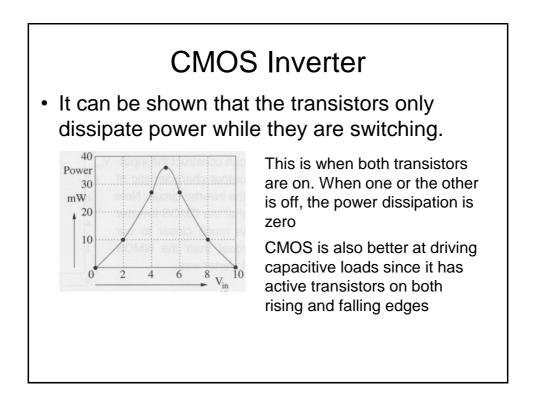


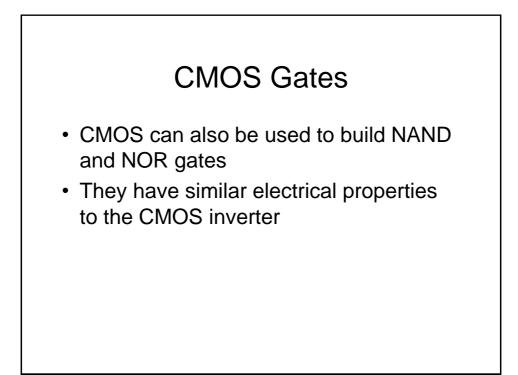


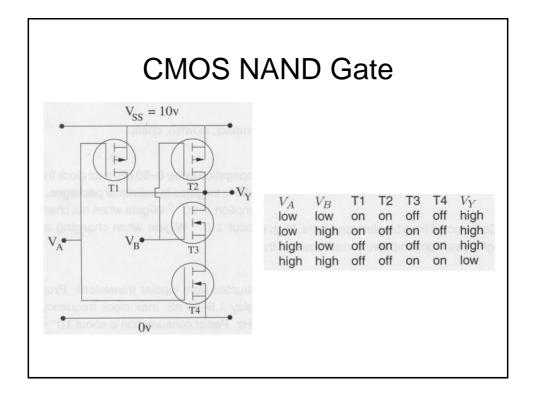




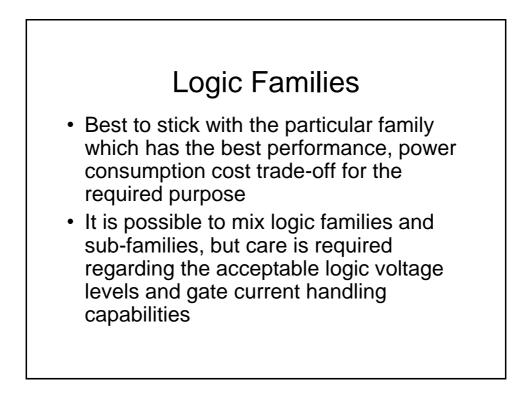








Logic Families NMOS – compact, slow, cheap, obsolete CMOS – Older families slow (4000 series about 60ns), but new ones (74AC) much faster (3ns). 74HC series popular TTL – Uses bipolar transistors. Known as 74 series. Note that most 74 series devices are now available in CMOS. Older versions slow (LS about 16ns), newer ones faster (AS about 2ns) ECL – High speed, but high power consumption



Meaning of Voltage Levels

- As we have seen, the relationship between the input voltage to a gate and the output voltage depends upon the particular implementation technology
- Essentially, the signals between outputs and inputs are 'analogue' and so are susceptible to corruption by additive noise, e.g., due to cross talk from signals in adjacent wires
- What we need is a method for quantifying the tolerance of a particular logic to noise

